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TPD2E009

Reference

Design

SLVS953B - JUNE 2009 - REVISED AUGUST 2015

TPD2E009 2-Channel ESD Solution for High-Speed (6-Gbps) Differential Interface

Technical

Documents

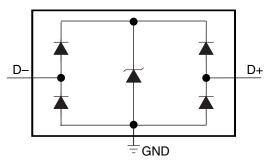
1 Features

- Supports Data Rates up to 6 Gbps
- IEC 61000-4-2 ESD Protection
 - ±8-kV Contact Discharge
 - ±8-kV Air-Gap Discharge
- IEC 61000-4-5 Surge Protection
 - 5 A (8/20 µs)
- Low Capacitance
 - DRT: 0.7-pF (Typ)
 - DBZ: 0.9-pF (Typ)
- 0.05-pF Matching Capacitance Between the **Differential Signal Pair**
- Dual-Matching TVS Diodes to Protect the Differential Data and Clock Lines of HDMI, LVDS, SATA, Ethernet, or USB Interfaces
- Space-Saving DRT and DBZ Package Options •
- Flow-Through Pin Mapping for the High-Speed • Lines Ensures Zero Additional Skew Due to Board Layout While Placing the ESD-Protection Chip Near the Connector

Applications 2

- End Equipment:
 - Notebooks
 - Set-Top Boxes
 - **Portable Computers**
 - DVD Players
 - _ Media Players
- Interfaces:
 - HDMI 2.0
 - **USB 3.0**
 - eSATA
 - Ethernet

TPD2E009 Circuit



3 Description

Tools &

Software

The TPD2E009 device provides two ESD protection diodes with flow-through pin mapping for ease of board layout. This device has been designed to protect sensitive components which are connected to ultra high-speed data and transmission lines. The TPD2E009 offers transient voltage suppression for Level 4 of IEC 61000-4-2 Contact ESD protection. TVS protection up to a 5-A (8/20 µs) peak pulsecurrent rating per the IEC 61000-4-5 (lightning) specification is also provided.

Support &

Community

2.2

The monolithic silicon technology allows matching between the differential signal pairs. The less than 0.05-pF differential capacitance ensures that the differential signal distortion due to added ESD circuit protection remains minimal. The low capacitance (0.7-pF) is suitable for high-speed data rates up to 6 Gbps.

The TPD2E009 TVS diode is offered in a DRT $(1 \text{ mm} \times 0.8 \text{ mm})$ package for space-saving portable applications. The industry standard DBZ (2.92 mm × 1.3 mm) package offers additional flexibility in the board layout for the system designer.

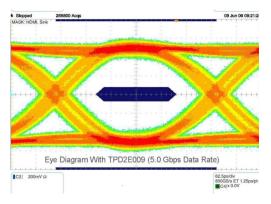
Typical applications for the TPD2E009 line of ESD protection products are: HDMI, USB, eSATA, and ethernet interfaces in notebooks, DVD and media players, set-top boxes, and portable computers.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)	
TPD2E009	SOT (2)	2.92 mm × 1.30 mm	
	SOT (3)	1.00 mm × 0.80 mm	

(1) For all available packages, see the orderable addendum at the end of the data sheet.

TPD2E009 Application Curve



TEXAS INSTRUMENTS

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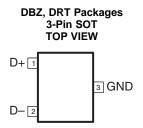
4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (June 2009) to Revision B



5 Pin Configuration and Functions



Pin Functions

1	PIN TYP		DESCRIPTION					
NAME	NO.	TIFE	DESCRIPTION					
D+	1		Link around ESD clamp provides ESD protection to the high around differential data lines					
D- 2		ESD port	High-speed ESD clamp provides ESD protection to the high-speed differential data lines					
GND	3	GND	Ground					

6 Specifications

6.1 Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
Operating temperature		-40	85	°C
I/O voltage tolerance		0	6	V
Peak pulse current ($t_p = 8/20 \ \mu s$)	D+, D– pins		5	А
Peak pulse power ($t_p = 8/20 \ \mu s$)			45	W
Storage temperature, T _{stg}		-65	125	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

				VALUE	UNIT
	Human body model (HBM), per ANSI/ESDA/JEDEC JS-00	±15000			
V	V _(ESD) Electrostatic discharge	Charged-device model (CDM), per JEDEC specification J	±1000	V	
V(ESD)		IEC 61000-4-2 contact discharge	D+, D– pins	±8000	v
		IEC 61000-4-2 air-gap discharge	D+, D– pins	±8000	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM MAX	UNIT
Operating free-air temperature,	, T _A	-40	85	°C
Operating voltage	Pin 1 or 2 to 3 or Pin 3 to 1 or 2	0	5.5	V

TPD2E009

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6.4 Thermal Information

		TPD	TPD2E009			
	THERMAL METRIC ⁽¹⁾	DBZ (SOT)	DRT (SOT)	UNIT		
		3 PINS	3 PINS			
$R_{\theta JA}$	Junction-to-ambient thermal resistance	461.8	610	°C/W		
R _{0JC(top)}	Junction-to-case (top) thermal resistance	216.2	288	°C/W		
$R_{\theta JB}$	Junction-to-board thermal resistance	195.6	118.4	°C/W		
Ψ _{JT}	Junction-to-top characterization parameter	70.1	20.2	°C/W		
Ψ _{JB}	Junction-to-board characterization parameter	193.7	116.4	°C/W		

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

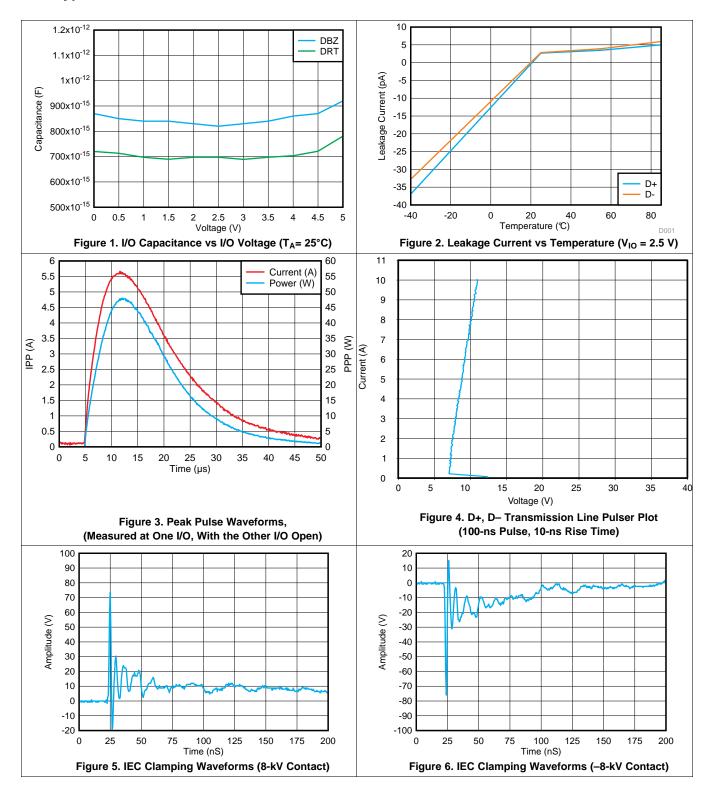
6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
V _{RWM}	Reverse stand-off voltage	D+, D– pins to ground				5.5	V
V _{CLAMP}	Clamp voltage	D+, D– pins to ground,	$I_{IO} = 1 A$			8	V
I _{IO}	Current from I/O port to supply pins	$V_{IO} = 2.5 V$			0.01	0.1	μA
V _D Di		D+, D– pins, lower clamp diode,	$V_{IO} = 2.5 \text{ V}, I_D = 8 \text{ mA}$	0.6	0.8	0.95	
	Diode forward voltage	D+, D– pins, upper clamp diode, DRY package	$V_{CC} = 0 V, I_D = -8 mA$	0.6	0.8	0.95	V
R _{DYN}	Dynamic resistance	D+, D– pins,	I = 1 A		1		Ω
C		D+, D– pins, DBZ Package	V _{IO} = 2.5 V, <i>f</i> = 10 MHz		0.9		pF
C _{IO}	I/O capacitance	D+, D– pins, DRT Package	V _{IO} = 2.5 V, <i>f</i> = 10 MHz		0.7		pF
V_{BR}	Break-down voltage	I _{IO} = 1 mA		7			V



6.6 Typical Characteristics



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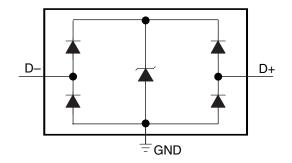
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7 Detailed Description

7.1 Overview

TPD2E009 is a two-channel ESD TVS that provides ±8-kV IEC 61000-4-2 contact and air-gap ESD protection. The 0.7-pF unidirectional diode architecture is suitable for signals that range from 0 V to 5.5 V and can support data rates up to 6 Gbps. The industry-standard packages are convenient for placement in applications with limited space.

7.2 Functional Block Diagram



7.3 Feature Description

TPD2E009 is a unidirectional TVS offering IEC 61000-4-2 Level 4 Contact ESD protection. This device protects circuits from ESD strikes up to \pm 8-kV contact and \pm 8-kV air-gap. The device can also handle up to 5-A surge current (IEC 61000-4-5 8/20 µs). The low capacitance of 0.7 pF supports a data rate up to 6 Gbps. TPD2E009 has a small dynamic resistance of 1 Ω , which makes the clamping voltage low when the device is actively protecting other circuits. For example, the clamping voltage is only 8 V when the device is taking a 1-A transient current. Low leakage allows the diode to conserve power when working below the V_{RWM}.

7.4 Device Functional Modes

The TPD2E009 device is a passive clamp that has low leakage during normal operation when the voltage between an I/O pin and GND is below V_{RWM} . The device activates when the voltage is between an I/O pin and GND goes above V_{BR} . During ESD events, transient voltages as high as ±8 kV can be clamped between the protected line and ground. When the voltages on the protected lines fall below the trigger voltage, the device reverts back to the low-leakage passive state.



8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The TPD2E009 device is a diode-array type TVS typically used to provide a path to ground for dissipating ESD events on high-speed signal lines between a human-interface connector and a system. As the current from ESD passes through the TVS, only a small voltage drop is present across the diode. This is the voltage presented to the protected IC. The low R_{DYN} of the triggered TVS holds this voltage, V_{CLAMP} , to a tolerable level to the protected IC.

8.2 Typical Application

The TPD2E009 device is typically used to protect a single high-speed differential pair. Multiple TPD2E009 devices can be used to provide protection for connectors with multiple differential data lanes. This example is applicable to many interface types including:

- HDMI
- USB
- eSATA
- ethernet interfaces

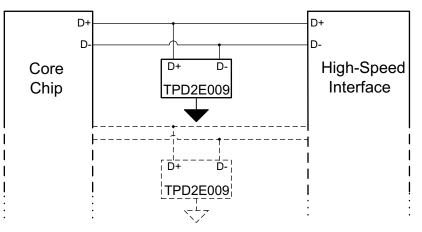


Figure 7. TPD2E009 in a High-Speed Interface

8.2.1 Design Requirements

For this design example, TPD2E009 is used to protect any differential data pair meeting the design requirements shown in the following table.

DESIGN PARAMETER	VALUE
Maximum signal range on D+ and D-	0 V to 5.5 V
Maximum Operating Frequency	3 GHz

8.2.2 Detailed Design Procedure

To begin the design process, some parameters must be decided upon; the designer must know the following:

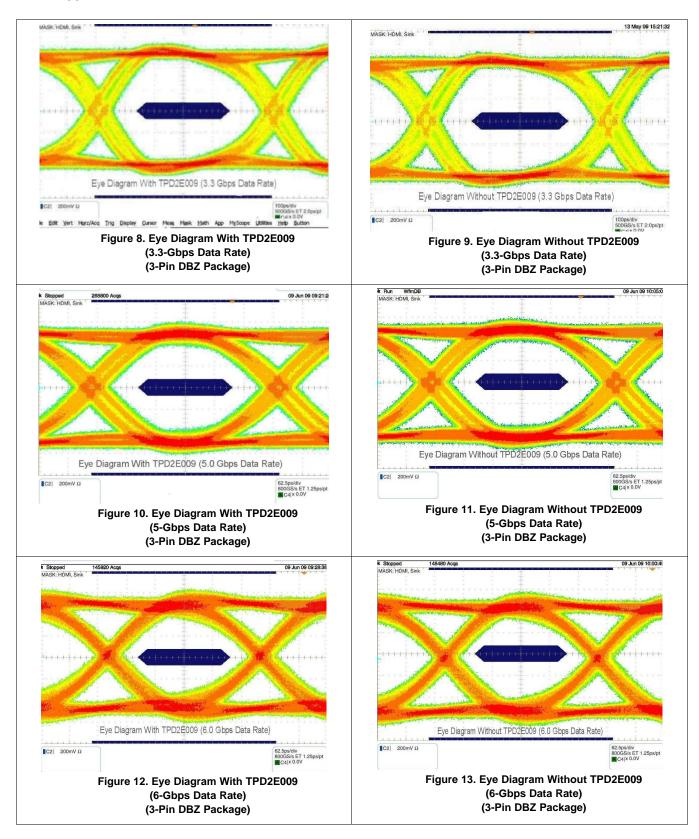
- The signal voltage range on the protected lines
- The maximum operating frequency

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8.2.3 Application Curves





9 Power Supply Recommendations

The TPD2E009 device is a passive ESD-protection device, and therefore, does not require a power supply. Care must be taken to avoid violating the maximum-voltage specification to ensure that the device functions properly. The D+ and D– lines share a TVS diode that can tolerate up to 5.5 V.

10 Layout

10.1 Layout Guidelines

Layout considerations such as package selection, trace routing, and so forth, must be accounted for while designing the ESD clamp circuit for a high-speed interface. Difficult routing can lead the designer to use vias or stubs in the board traces, which creates significant disruption in the line impedance in the high-speed signal path. Poor package choice can force the designer to route differential traces with unequal lengths and add the skew in the signals. TI recommends coupling the differential traces closely to reduce the EMI interference.

The TPD2E009 can provide system-level ESD protection to the high-speed differential ports (up to 6-Gbps data rate). The flow-through package offers flexibility for board routing with traces up to 15 mils (0.38 mm) wide. Figure 14 and Figure 15 show the board layout scheme for the D+ and D– lines of a single differential pair, which allows the differential signal pairs to couple together right after they touch the ESD ports (pin 1 and pin 2) of the TPD2E009.

10.2 Layout Examples

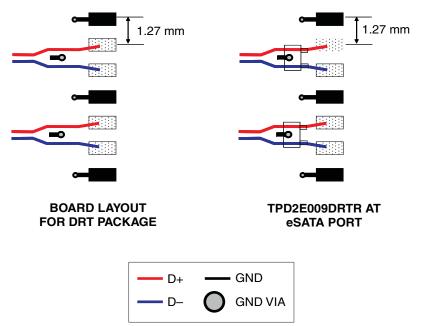


Figure 14. TPD2E009DRTR at eSATA Connector Interface



Layout Examples (continued)

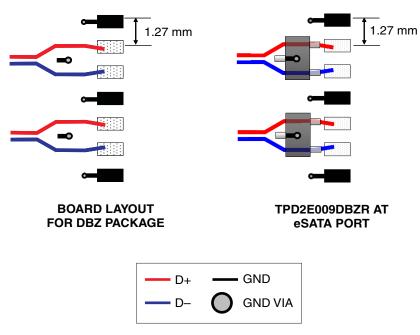


Figure 15. TPD2E009DBZR at eSATA Connector Interface



11 Device and Documentation Support

11.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E[™] Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.2 Trademarks

E2E is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

11.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
TPD2E009DBZR	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	(NFLO, NFLR)
TPD2E009DBZR.B	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	(NFLO, NFLR)
TPD2E009DBZRG4.B	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	NFLR
TPD2E009DRTR	Active	Production	SOT-9X3 (DRT) 3	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	4T
TPD2E009DRTR.B	Active	Production	SOT-9X3 (DRT) 3	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	4T
TPD2E009DRTRG4.B	Active	Production	SOT-9X3 (DRT) 3	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	4T

⁽¹⁾ **Status:** For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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PACKAGE OPTION ADDENDUM

23-May-2025

PACKAGE MATERIALS INFORMATION

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Texas Instruments

TAPE AND REEL INFORMATION



*All dimensions are nominal



QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPD2E009DBZR	SOT-23	DBZ	3	3000	180.0	8.4	3.15	2.77	1.22	4.0	8.0	Q3
TPD2E009DRTR	SOT-9X3	DRT	3	3000	180.0	8.4	1.16	1.16	0.63	4.0	8.0	Q3

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PACKAGE MATERIALS INFORMATION

15-Feb-2018



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPD2E009DBZR	SOT-23	DBZ	3	3000	183.0	183.0	20.0
TPD2E009DRTR	SOT-9X3	DRT	3	3000	202.0	201.0	85.0

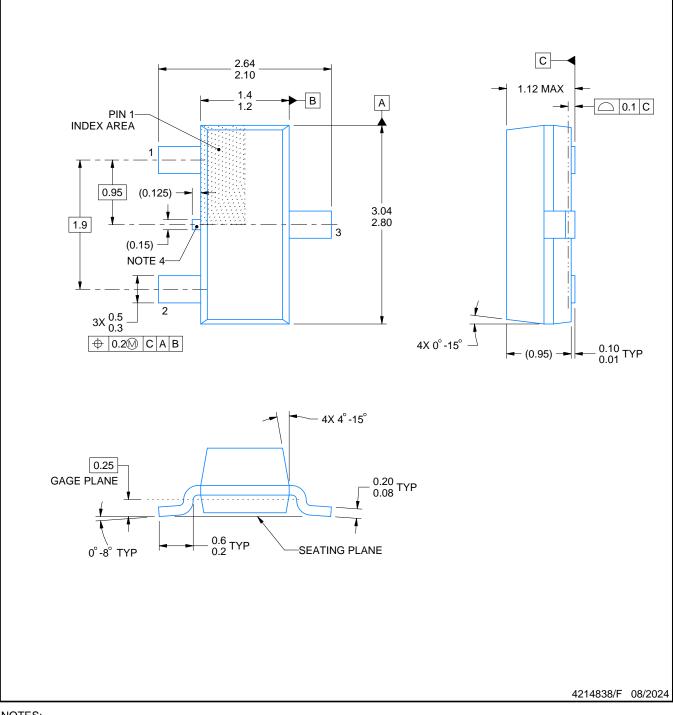
DBZ0003A



PACKAGE OUTLINE

SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC registration TO-236, except minimum foot length.

- 4. Support pin may differ or may not be present.
- 5. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side

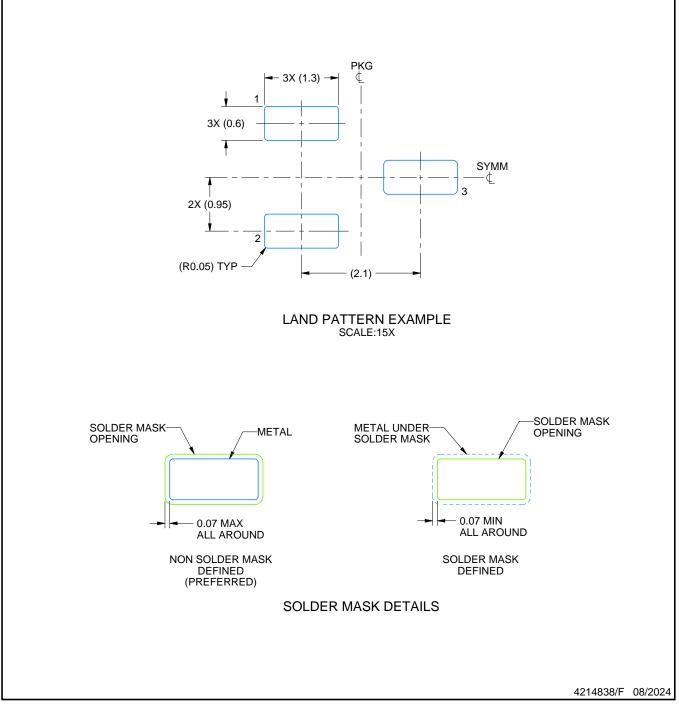


DBZ0003A

EXAMPLE BOARD LAYOUT

SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

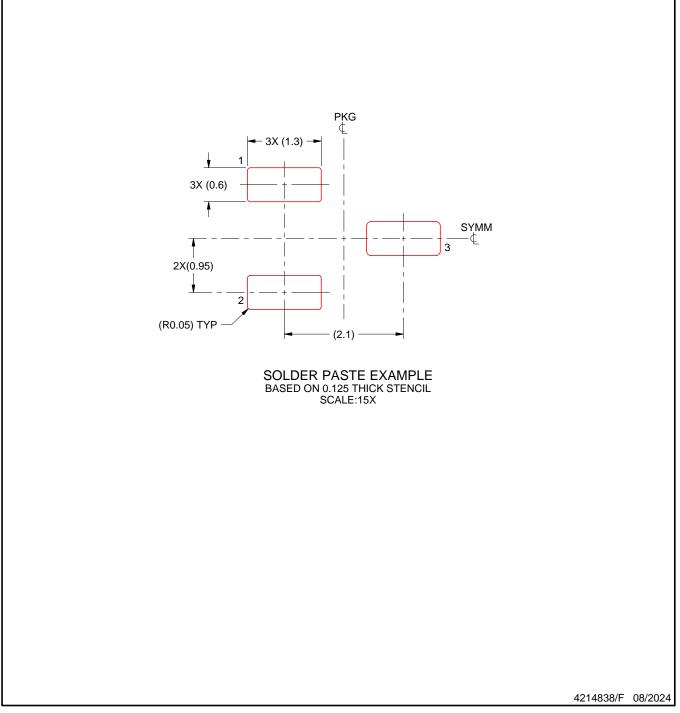


DBZ0003A

EXAMPLE STENCIL DESIGN

SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

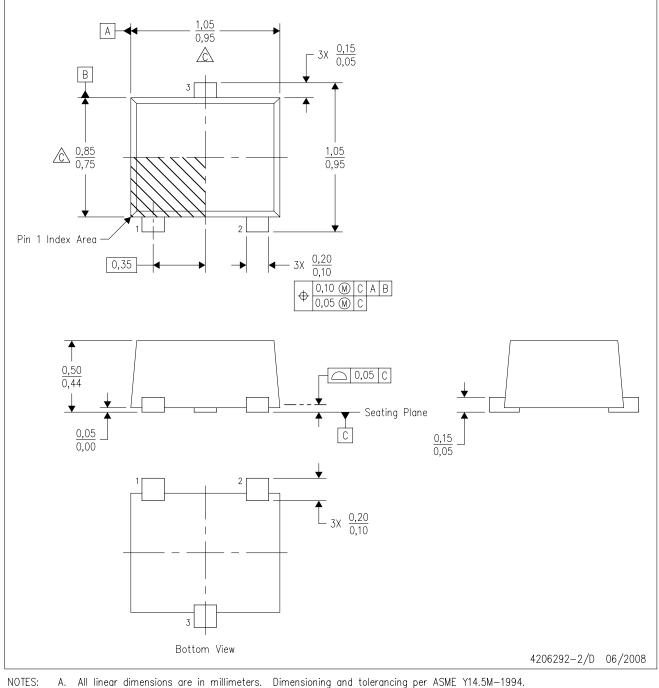
7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

8. Board assembly site may have different recommendations for stencil design.



DRT (R-PDSO-N3)

PLASTIC SMALL OUTLINE



Α. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

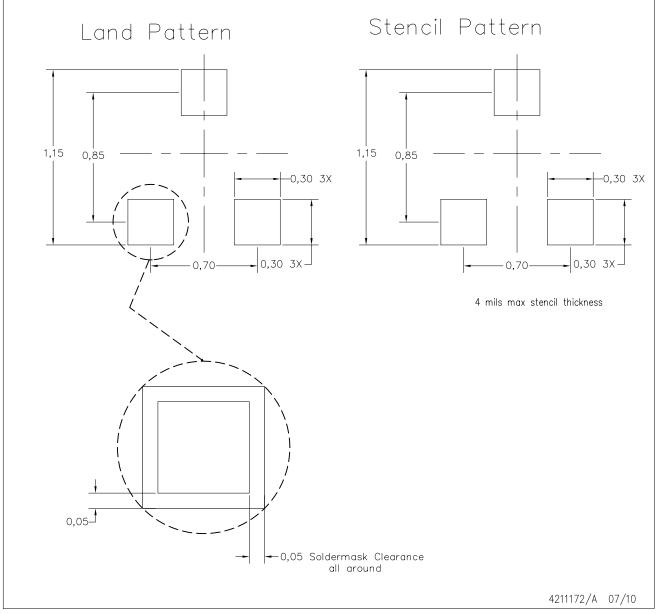
- Β. This drawing is subject to change without notice.
- Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs. Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0,10 per end or side.
- D. JEDEC package registration is pending.



LAND PATTERN

DRT (S-PDSO-N3)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
- E. Maximum stencil thickness 0,1016 mm (4 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Side aperture dimensions over-print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.



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